**Preferred Device** 

# Small Signal MOSFET 500 mA, 60 Volts

**N-Channel TO-92 (TO-226)** 

## **Features**

• Pb-Free Package is Available\*

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	Vdc
$\label{eq:Gate-Source Voltage} \begin{tabular}{ll} Gate-Source Voltage \\ - Continuous \\ - Non-repetitive (t_p \le 50~\mu s) \end{tabular}$	V <sub>GS</sub> V <sub>GSM</sub>	±20 ±40	Vdc Vpk
Drain Current (Note)	I <sub>D</sub>	0.5	Adc
Total Device Dissipation @ T <sub>A</sub> = 25°C	P <sub>D</sub>	350	mW
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

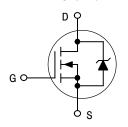
NOTE: The Power Dissipation of the package may result in a lower continuous drain current.



# ON Semiconductor®

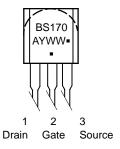
500 mA, 60 Volts  $R_{DS(on)} = 5.0 \Omega$ 

## N-Channel





# MARKING DIAGRAM & PIN ASSIGNMENT



BS170 = Device Code A = Assembly Location Y = Year

Y = Year WW = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **BS170**

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•	•	•
Gate Reverse Current (V <sub>GS</sub> = 15 Vdc, V <sub>DS</sub> = 0)	I <sub>GSS</sub>	-	0.01	10	nAdc
Drain–Source Breakdown Voltage $(V_{GS} = 0, I_D = 100 \mu Adc)$	V <sub>(BR)DSS</sub>	60	90	-	Vdc
ON CHARACTERISTICS (Note 1)					
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 1.0 \text{ mAdc})$	V <sub>GS(Th)</sub>	0.8	2.0	3.0	Vdc
Static Drain–Source On Resistance (V <sub>GS</sub> = 10 Vdc, I <sub>D</sub> = 200 mAdc)	r <sub>DS(on)</sub>	-	1.8	5.0	Ω
Drain Cutoff Current (V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0 Vdc)	I <sub>D(off)</sub>	-	-	0.5	μΑ
Forward Transconductance (V <sub>DS</sub> = 10 Vdc, I <sub>D</sub> = 250 mAdc)	9 <sub>fs</sub>	-	200	_	mmhos
SMALL-SIGNAL CHARACTERISTICS					
Input Capacitance (V <sub>DS</sub> = 10 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>iss</sub>	-	_	60	pF
SWITCHING CHARACTERISTICS	-		-		-
Turn-On Time (I <sub>D</sub> = 0.2 Adc) See Figure 1	t <sub>on</sub>	-	4.0	10	ns
Turn-Off Time (I <sub>D</sub> = 0.2 Adc) See Figure 1	t <sub>off</sub>	-	4.0	10	ns

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

# **ORDERING INFORMATION**

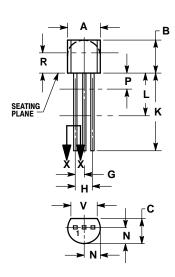
Device	Package	Shipping <sup>†</sup>
BS170	TO-92 (TO-226)	1000 Unit/Tube
BS170G	TO-92 (TO-226) (Pb-Free)	1000 Unit/Tube
BS170RLRA	TO-92 (TO-226)	2000 Tape & Reel
BS170RLRAG	TO-92 (TO-226) (Pb-Free)	2000 Tape & Reel
BS170RLRM	TO-92 (TO-226)	2000 Tape & Reel
BS170RLRMG	TO-92 (TO-226) (Pb-Free)	2000 Tape & Reel
BS170RLRP	TO-92 (TO-226)	2000 Tape & Reel
BS170RLRPG	TO-92 (TO-226) (Pb-Free)	2000 Tape & Reel
BS170RL1	TO-92 (TO-226)	2000 Tape & Reel
BS170RL1G	TO-92 (TO-226) (Pb-Free)	2000 Tape & Reel
BS170ZL1	TO-92 (TO-226)	2000 Tape & Reel
BS170ZL1G	TO-92 (TO-226) (Pb-Free)	2000 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **BS170**

# **PACKAGE DIMENSIONS**

# TO-92 (TO-226) CASE 29-11 ISSUE AL





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

- STYLE 30:
  PIN 1. DRAIN
  2. GATE
  3. SOURCE